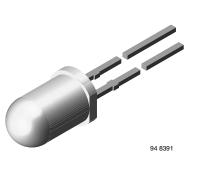
Vishay Semiconductors

Silicon NPN Phototransistor



www.vishay.com

DESCRIPTION

BPW96 is a silicon NPN phototransistor with high radiant sensitivity in clear, T-1¾ plastic package. It is sensitive to visible and near infrared radiation.

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Leads with stand-off
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 20^{\circ}$
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

• Detector in electronic control and drive circuits

PRODUCT SUMMARY						
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.1} (nm)			
BPW96B	2.5 to 7.5	± 20	450 to 1080			
BPW96C	4.5 to 15	± 20	450 to 1080			

Note

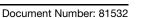
Test condition see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
BPW96B	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
BPW96C	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Collector emitter voltage		V _{CEO}	70	V		
Emitter collector voltage		V _{ECO}	5	V		
Collector current		Ι _C	50	mA		
Collector peak current	$t_p/T \le 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA		
Power dissipation	$T_{amb} \le 47 \ ^{\circ}C$	Pv	150	mW		
Junction temperature		Тj	100	°C		
Operating temperature range		T _{amb}	- 40 to + 100	°C		
Storage temperature range		T _{stg}	- 40 to + 100	°C		
Soldering temperature	t ≤ 3 s	T _{sd}	260	°C		
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W		



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COMPLIANT

GREEN (5-2008)**



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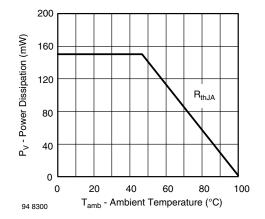


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Collector emitter breakdown voltage	I _C = 1 mA	V _{(BR)CEO}	70			V	
Collector emitter dark current	$V_{CE} = 20 \text{ V}, \text{ E} = 0$	I _{CEO}		1	200	nA	
Collector emitter capacitance	$V_{CE} = 5 V, f = 1 MHz, E = 0$	C _{CEO}		3		pF	
Angle of half sensitivity		φ		± 20		deg	
Wavelength of peak sensitivity		λρ		850		nm	
Range of spectral bandwidth		λ _{0.1}		450 to 1080		nm	
Collector emitter saturation voltage	$\begin{array}{l} E_{e} = 1 \ mW/cm^2, \lambda = 950 \ nm, \\ I_C = 0.1 \ mA \end{array}$	V _{CEsat}			0.3	V	
Turn-on time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{on}		2.0		μs	
Turn-off time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{off}		2.3		μs	
Cut-off frequency	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω	f _c		180		kHz	

TYPE DEDICATED CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector light current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$,	BPW96B	I _{ca}	2.5	4.5	7.5	mA
	$V_{CE} = 5 V$	BPW96C	I _{ca}	4.5	8	15	mA





BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

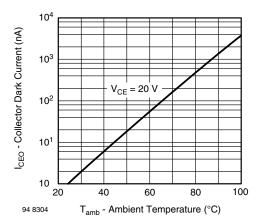


Fig. 1 - Collector Dark Current vs. Ambient Temperature

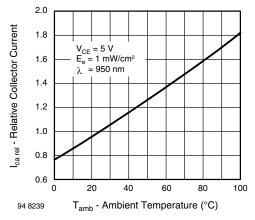


Fig. 2 - Relative Collector Current vs. Ambient Temperature

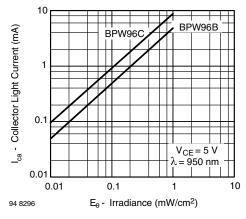


Fig. 3 - Collector Light Current vs. Irradiance

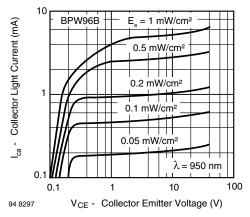


Fig. 4 - Collector Light Current vs. Collector Emitter Voltage

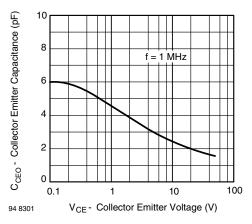


Fig. 5 - Collector Emitter Capacitance vs. Collector Emitter Voltage

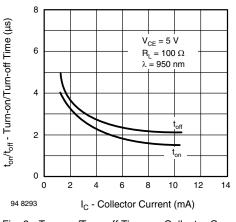


Fig. 6 - Turn-on/Turn-off Time vs. Collector Current

Rev. 1.8, 23-Aug-11

3 For technical questions, contact: <u>detectortechsupport@vishay.com</u> Document Number: 81532

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BPW96B, BPW96C

Vishay Semiconductors

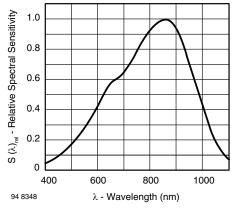


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

PACKAGE DIMENSIONS in millimeters

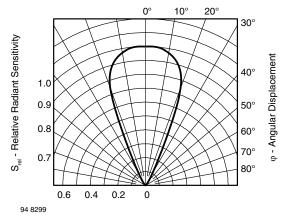
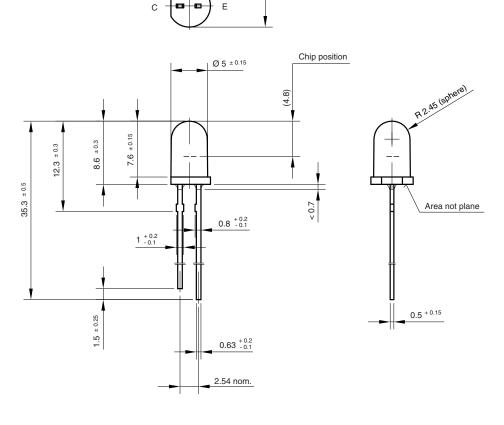


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement



 5.75 ± 0.15

Drawing-No.: 6.544-5086.01-4 Issue:1; 01.07.96 96 12192

Rev. 1.8, 23-Aug-11

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technical drawings according to DIN specifications



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